

ATTY. DOCKET NO.

4495-2

APPLICANT

SUZUKI et al

FILING DATE

March 2, 2004

SERIAL NO.

10/790,238

EXAMINER

MURSALIN B. HAFIZ

GROUP

2814

(Use several sheets if necessary)

U.S. PATENT DOCUMENTS

[illegible]

FOREIGN PATENT DOCUMENTS

							TRANSLATION	
DOCUMENT			DATE	COUNTRY	CLASS	SUBCLASS	YES	NO
Mbh		10-261291 A	9-1998	JP	—	—	partial	
Mbh		10-255481 A	9-1998	JP	—	—	partial	

OTHER DOCUMENTS (including Author, Title, Date, Pertinent pages, etc.)

Mbh	Liu, "Electric-Pulse-Induced Reversible Resistance Change Effect in Magnetoresistive Films", Applied Physics Letters, Vol. 76, No. 19, 8 May 2000, American Institute of Physics, pp. 2749-2751
Mbh	Miyake, "Flash Memory vs. New Nonvolatile Memory, Part 2 (Flash Memory Overwhelming Stand-Alone, and New Promising "RRAM")", Nikkei Microdevices, January 2003, pp. 72-83 and partial English transmittal

*Examiner

Muralis Biru Hafiz

Date Considered

10/26/05

Examiner: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to application.

Form PTO-FB-A820 (Also PTO-1449)